



SEMITOP®E1

Sixpack Open Emitter

Engineering Sample SK20GD07E3ETE1

Target Data

Features*

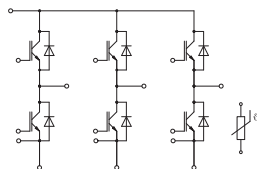
- Optimized design for superior thermal performance
- Low inductive design
- Press-Fit contact technology
- 650V Trench IGBT3 (E3)
- Robust and soft switching CAL4F diode technology
- Integrated NTC temperature sensor
- UL recognized file no. E 63 532

Typical Applications

- Motor drives
- Servo drives
- Air conditioning
- Auxiliary Inverters
- UPS

Remarks

- Recommended $T_{j,op} = -40 \dots +150 \text{ °C}$



GD-ET

Absolute Maximum Ratings				
Symbol	Conditions	Values	Unit	
Inverter - IGBT				
V_{CES}	$T_j = 25 \text{ °C}$	650	V	
I_C	$\lambda_{paste}=0.8 \text{ W/(mK)}$	$T_s = 25 \text{ °C}$	27	A
	$T_j = 175 \text{ °C}$	$T_s = 70 \text{ °C}$	22	A
I_C	$\lambda_{paste}=2.5 \text{ W/(mK)}$	$T_s = 25 \text{ °C}$	31	A
	$T_j = 175 \text{ °C}$	$T_s = 70 \text{ °C}$	25	A
I_{Cnom}		20	A	
I_{CRM}		40	A	
V_{GES}		-20 ... 20	V	
t_{psc}	$V_{CC} = 360 \text{ V}$	$T_j = 150 \text{ °C}$	6	μs
	$V_{GE} \leq 15 \text{ V}$			
	$V_{CES} \leq 650 \text{ V}$			
T_j		-40 ... 175		$^{\circ}\text{C}$
Inverse - Diode				
V_{RRM}	$T_j = 25 \text{ °C}$	650	V	
I_F	$\lambda_{paste}=0.8 \text{ W/(mK)}$	$T_s = 25 \text{ °C}$	33	A
	$T_j = 175 \text{ °C}$	$T_s = 70 \text{ °C}$	26	A
I_F	$\lambda_{paste}=2.5 \text{ W/(mK)}$	$T_s = 25 \text{ °C}$	37	A
	$T_j = 175 \text{ °C}$	$T_s = 70 \text{ °C}$	29	A
I_{FRM}		60	A	
I_{FSM}	$t_p = 10 \text{ ms, sin } 180^{\circ}, T_j = 150 \text{ °C}$	150	A	
T_j		-40 ... 175	$^{\circ}\text{C}$	
Module				
$I_{t(RMS)}$	$\Delta T_{terminal}$ at PCB joint = 30 K, per pin	30	A	
T_{stg}	module without TIM	-40 ... 125	$^{\circ}\text{C}$	
V_{isol}	AC, sinusoidal, $t = 1 \text{ min}$	2500	V	

Characteristics					
Symbol	Conditions	min.	typ.	max.	Unit
Inverter - IGBT					
$V_{CE(sat)}$	$I_C = 20 \text{ A}$ $V_{GE} = 15 \text{ V}$ chipelevel	$T_j = 25 \text{ °C}$	1.45	1.87	V
		$T_j = 150 \text{ °C}$	1.83	2.10	V
V_{CE0}	chipelevel	$T_j = 25 \text{ °C}$	0.90	1.00	V
		$T_j = 150 \text{ °C}$	0.82	0.90	V
r_{CE}	$V_{GE} = 15 \text{ V}$ chipelevel	$T_j = 25 \text{ °C}$	28	44	$\text{m}\Omega$
		$T_j = 150 \text{ °C}$	51	60	$\text{m}\Omega$
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 0.29 \text{ mA}$	5.1	5.8	6.4	V
I_{CES}	$V_{GE} = 0 \text{ V}, V_{CE} = 650 \text{ V}, T_j = 25 \text{ °C}$			0.2	mA
C_{ies}	$V_{CE} = 25 \text{ V}$ $V_{GE} = 0 \text{ V}$	$f = 1 \text{ MHz}$	1.1		nF
C_{oes}		$f = 1 \text{ MHz}$	0.071		nF
C_{res}		$f = 1 \text{ MHz}$	0.032		nF
Q_G	$V_{GE} = -15\text{V} \dots +15\text{V}$		200		nC
R_{Gint}	$T_j = 25 \text{ °C}$		0		Ω
$t_{d(on)}$	$V_{CC} = 300 \text{ V}$ $I_C = 20 \text{ A}$	$T_j = 150 \text{ °C}$	14		ns
t_r		$T_j = 150 \text{ °C}$	23		ns
E_{on}	$R_{G on} = 12 \text{ }\Omega$ $R_{G off} = 12 \text{ }\Omega$	$T_j = 150 \text{ °C}$	0.37		mJ
$t_{d(off)}$	$di/dt_{on} = 927 \text{ A}/\mu\text{s}$ $di/dt_{off} = 298 \text{ A}/\mu\text{s}$	$T_j = 150 \text{ °C}$	148		ns
t_f		$T_j = 150 \text{ °C}$	34		ns
E_{off}	$V_{GE} = +15/-15 \text{ V}$	$T_j = 150 \text{ °C}$	0.67		mJ
$R_{th(j-s)}$	per IGBT, $\lambda_{paste}=0.8 \text{ W/(mK)}$		2.07		K/W
$R_{th(j-s)}$	per IGBT, $\lambda_{paste}=2.5 \text{ W/(mK)}$		1.71		K/W



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Typical Applications

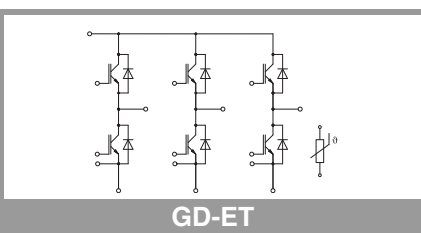
- Motor drives
- Servo drives
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Remarks

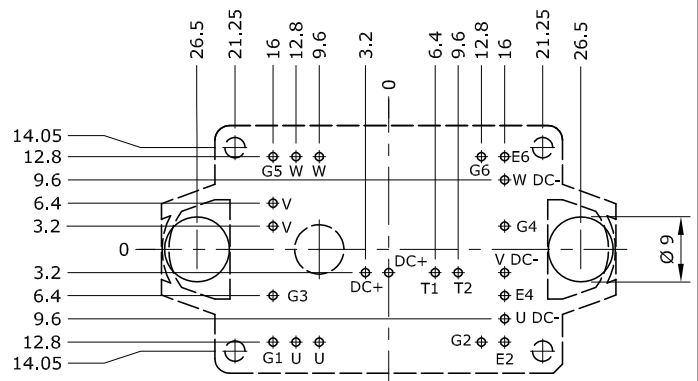
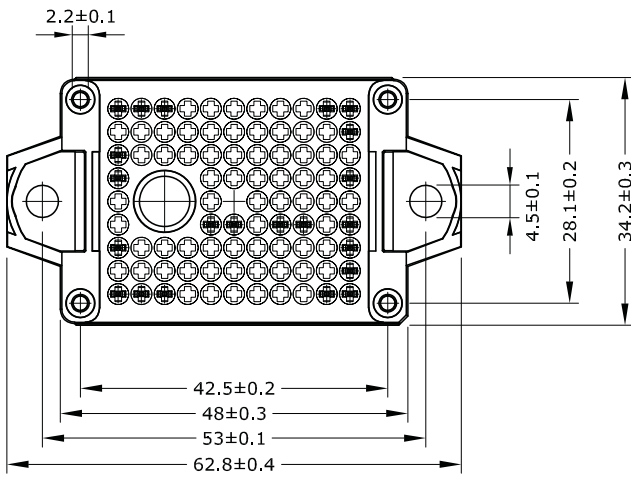
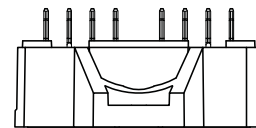
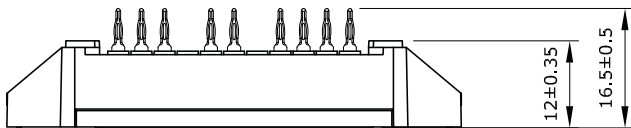
- Recommended $T_{j,op} = -40 \dots +150 \text{ °C}$

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
Inverse - Diode						
$V_F = V_{EC}$	$I_F = 20 \text{ A}$	$T_j = 25 \text{ °C}$		1.41	1.78	V
		chiplevel $T_j = 150 \text{ °C}$		1.41	1.80	V
V_{F0}	chiplevel	$T_j = 25 \text{ °C}$		1.04	1.24	V
		$T_j = 150 \text{ °C}$		0.85	0.99	V
r_F	chiplevel	$T_j = 25 \text{ °C}$		19	27	mΩ
		$T_j = 150 \text{ °C}$		28	41	mΩ
I_{RRM}	$I_F = 20 \text{ A}$	$T_j = 150 \text{ °C}$		30		A
Q_{rr}	$V_{GE} = +15/-15 \text{ V}$ $V_{CC} = 300 \text{ V}$	$T_j = 150 \text{ °C}$		1.33		μC
E_{rr}	$di/dt_{off} = 930 \text{ A/μs}$	$T_j = 150 \text{ °C}$		0.13		mJ
$R_{th(j-s)}$	per Diode, $\lambda_{paste} = 0.8 \text{ W/(mK)}$			2.07		K/W
$R_{th(j-s)}$	per Diode, $\lambda_{paste} = 2.5 \text{ W/(mK)}$			1.71		K/W
Module						
L_{CE}				30		nH
M_s	to heatsink		1.6		2.3	Nm
w				25		g

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
Temperature Sensor						
R_{100}	$T_c = 100 \text{ °C}$ ($R_{25} = 5 \text{ kΩ}$)			$493 \pm 5\%$		Ω
$B_{25/85}$	$R_{(T)} = R_{25} \cdot \exp[B_{25/85} \cdot (1/T - 1/298)]$, T[K]			3420		K

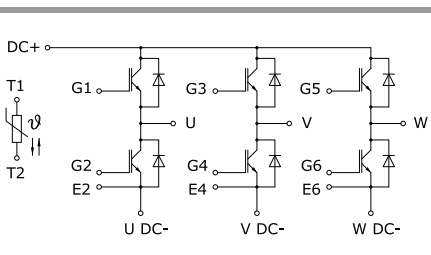


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- Pin-Grid 3.2 mm
- Tolerance of PCB hole pattern ± 0.1
- Diameters of drill $\varnothing 1.15\text{mm}$
- Copper thickness in hole 25 - 50 μm
- Hole specification for contacts:
refer to SEMITOP E1/E2 Mounting Instruction

SEMITOP®E1



GD-ET

This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

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